RoHS

Vishay General Semiconductor

Surface Mount Ultrafast Plastic Rectifier



DO-214AA (SMB)

PRIMARY CHARACTERISTICS						
I _{F(AV)} 2.0 A						
V _{RRM}	50 V to 200 V					
I _{FSM}	50 A					
t _{rr}	20 ns					
V _F	0.90 V					
T _J max.	150 °C					

FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- · Ultrafast recovery times for high efficiency
- Low forward voltage, low power losses
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, automotive and telecommunication.

MECHANICAL DATA

Case: DO-214AA (SMB)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

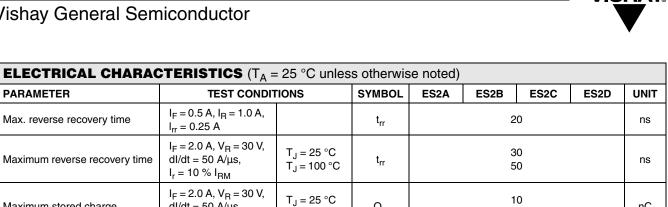
MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL	ES2A	ES2B	ES2C	ES2D	UNIT	
Device marking code		EA	EB	EC	ED		
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	V	
Maximum RMS voltage	V _{RMS}	35	70	105	140	V	
Maximum DC blocking voltage	V _{DC}	50	100	150	200	V	
Maximum average forward rectified current at $T_L = 110 \ ^\circ C$	I _{F(AV)}	2.0					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	50				A	
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150					

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)

PARAMETER	TEST CONDITIONS		SYMBOL	ES2A	ES2B	ES2C	ES2D	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	2.0 A		V _F	0.90				V
Maximum DC reverse current at rated DC blocking voltage		T _A = 25 °C T _A = 100 °C	I _R	10 350			μΑ	

For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com

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Q_{rr}

CJ

10

25

18

nC

pF

NI	-	ła	

PARAMETER

Max. reverse recovery time

Maximum stored charge

Typical junction capacitance

(1) Pulse test: 300 ms pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_A = 25 \degree C$ unless otherwise noted)							
PARAMETER	SYMBOL	ES2A	ES2B	ES2C	ES2D	UNIT	
Typical thermal resistance ⁽¹⁾	$R_{ extsf{ heta}JA} \ R_{ extsf{ heta}JL}$	75 20				°C/W	

T_J = 100 °C

Note:

(1) Units mounted on P.C.B. 5.0 x 5.0 mm (0.013 mm thick) land areas

 $dI/dt = 50 A/\mu s$,

 $I_r = 10 \% I_{BM}$ 4.0 V, 1 MHz

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
ES2D-E3/52T	0.096	52T	750	7" diameter plastic tape and reel			
ES2D-E3/5BT	0.096	5BT	3200	13" diameter plastic tape and reel			
ES2DHE3/52T (1)	0.096	52T	750	7" diameter plastic tape and reel			
ES2DHE3/5BT ⁽¹⁾	0.096	5BT	3200	13" diameter plastic tape and reel			

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

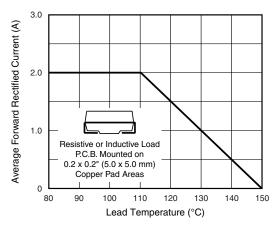


Figure 1. Maximum Forward Current Derating Curve

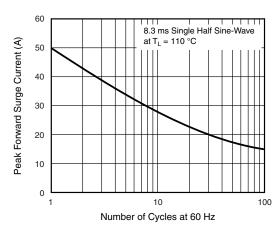


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



ES2A thru ES2D

= 25 °C T,

= 50 mVp-p

100

f = 1.0 MHz

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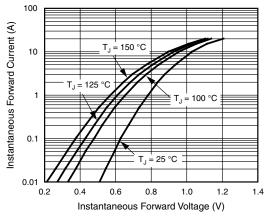
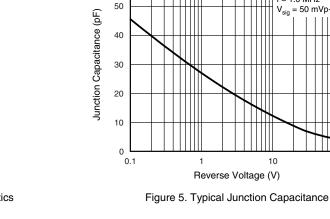


Figure 3. Typical Instantaneous Forward Characteristics



60

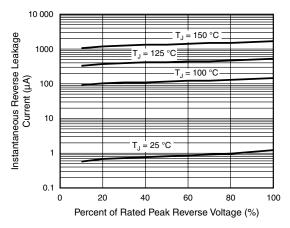
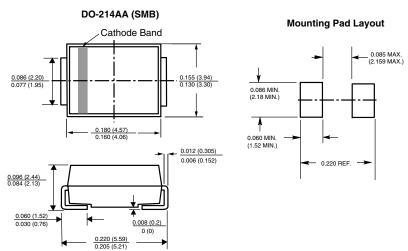


Figure 4. Typical Reverse Leakage Characteristics

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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